

SILICON VARACTOR DIODE

DESCRIPTION:

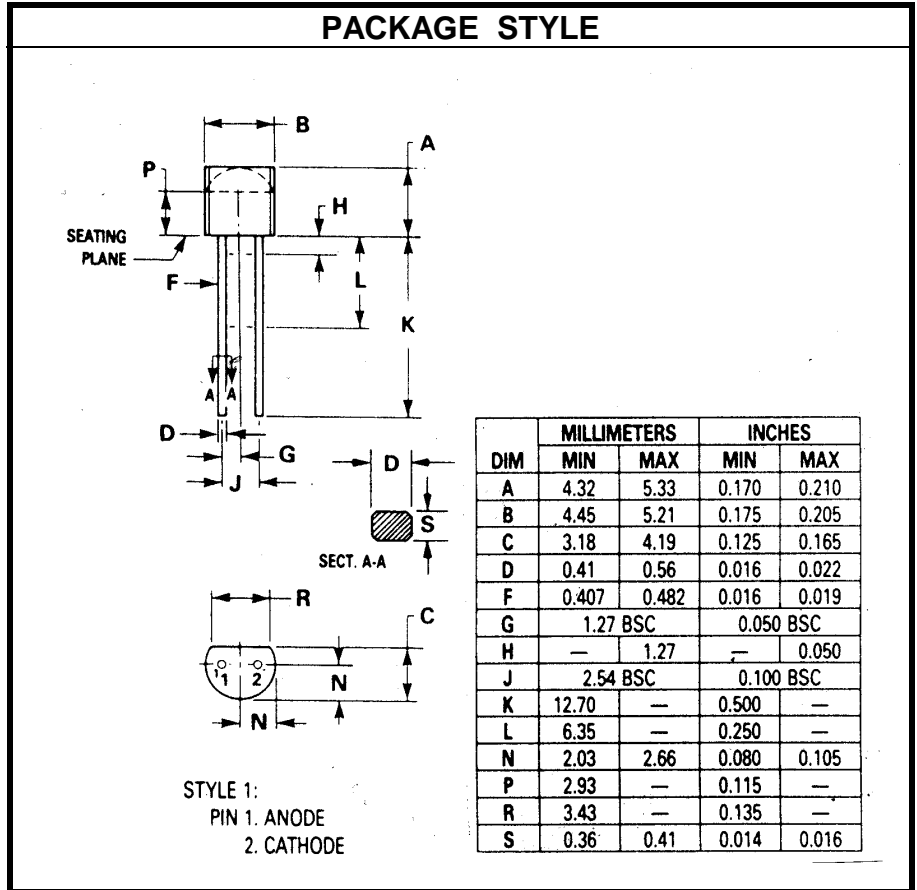
The **ASI MVAM108** is a Silicon Tuning Varactor Diode.

FEATURES INCLUDE:

- 15:1 Minimum Tuning Range
- Q - 150 Minimum

MAXIMUM RATINGS

I_F	50 mA
V_R	12 V
P_{DISS}	280 mW @ $T_C = 25^\circ C$
T_J	$-55^\circ C$ to $+125^\circ C$
T_{STG}	$-55^\circ C$ to $+125^\circ C$


CHARACTERISTICS $T_A = 25^\circ C$

SYMBOL	TEST CONDITIONS	MINIMUM	TYPICAL	MAXIMUM	UNITS
V_{BR}	$I_R = 10 \mu A$	12			V
I_R	$V_R = 8.0 V$			0.10	μA
C_t	$V_R = 1.0 V$		$f = 1.0 MHz$	560	pF
C_{T1}/C_{T8}			$f = 1.0 MHz$		---
Q	$V_R = 1.0 V$		$f = 1.0 MHz$	150	---